2SB0948 (2SB948), 2SB0948A (2SB948A)

Silicon PNP epitaxial planar type

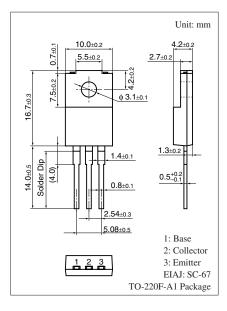
For low-voltage switching

Features

- Low collector-emitter saturation voltage $V_{CE(sat)}$
- High-speed switching
- Full-pack package which can be installed to the heat sink with one screw

Parameter	Symbol	Rating	Unit	
Collector-base voltage	2SB0948	V _{CBO}	-40	V
(Emitter open)	2SB0948A		-50	
Collector-emitter voltage	2SB0948	V _{CEO}	-20	V
(Base open)	2SB0948A		-40	
Emitter-base voltage (Coll	V _{EBO}	-5	V	
Collector current	I _C	-10	А	
Peak collector current	I _{CP}	-20	А	
Collector power dissipatio	P _C	40	W	
	$T_a = 25^{\circ}C$		2	
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	





Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

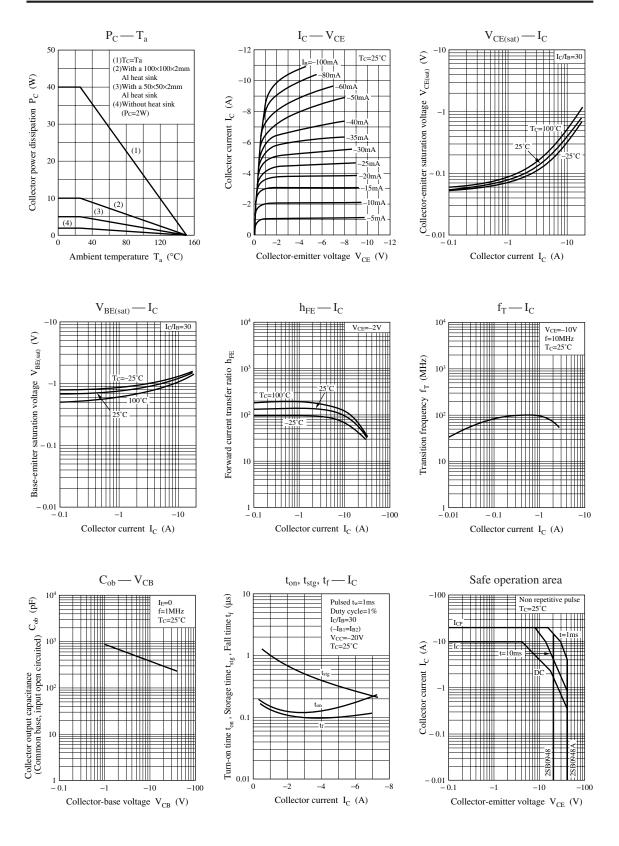
Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage	2SB0948	V _{CEO}	$I_{\rm C} = -10 \text{ mA}, I_{\rm B} = 0$	-20			V
(Base open)	2SB0948A			-40			
Collector-base cutoff current (Emitter open)		I _{CBO}	$V_{CB} = -40 \text{ V}, I_E = 0$			-50	μΑ
Emitter-base cutoff current (Collector open)		I_{EBO}	$V_{EB} = -5 V, I_C = 0$			-50	μΑ
Forward current transfer ratio		h _{FE1}	$V_{CE} = -2 V, I_C = -0.1 A$	45			
		h _{FE2} *	$V_{CE} = -2 V, I_C = -3 A$	60		260	
Collector-emitter saturation voltage		V _{CE(sat)}	$I_{\rm C} = -10$ A, $I_{\rm B} = -0.33$ A			- 0.6	V
Base-emitter saturation voltage		V _{BE(sat)}	$I_{\rm C} = -10 \text{ A}, I_{\rm B} = -0.33 \text{ A}$			-1.5	V
Transition frequency		f_{T}	$V_{CE} = -10 \text{ V}, I_C = -0.5 \text{ A}, f = 10 \text{ MHz}$		100		MHz
Collector output capacitance		C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		400		pF
(Common base, input open circuited)							
Turn-on time		t _{on}	$I_C = -3 A$, $I_{B1} = -0.1 A$, $I_{B2} = 0.1 A$		0.1		μs
Storage time		t _{stg}	$V_{\rm CC} = -20 \text{ V}$		0.5		μs
Fall time		t _f			0.1		μs

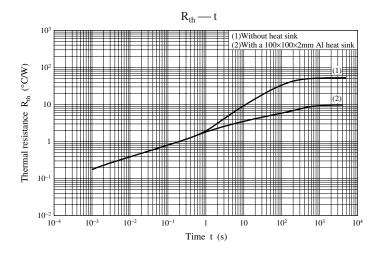
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors. 2. *: Rank classification

Rank	R	Q	Р	
h _{FE2}	60 to 120	90 to 180	130 to 260	

Note) The part numbers in the parenthesis show conventional part number.

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